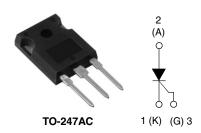


Vishay High Power Products

Phase Control SCR, 35 A



PRODUCT SUMMARY				
V _T at 40 A	< 1.45 V			
I _{TSM}	500 A			
V _{RRM}	800/1200 V			

DESCRIPTION/FEATURES

The 40TPS...A High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature. Low Igt parts available.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS VALUES		UNITS		
I _{T(AV)}	Sinusoidal waveform	35	Α		
I _{RMS}		55	A		
V _{RRM} /V _{DRM}		800/1200	V		
I _{TSM}		500	А		
V _T	40 A, T _J = 25 °C	1.45	V		
dV/dt		1000	V/µs		
dl/dt		100	A/μs		
TJ		- 40 to 125	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
40TPS08A	800	900			
40TPS12A	1200	10			
40TPS08	800	900	10		
40TPS12	1200	1300			

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PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 79 °C, 180° conduction half sine wave		35		
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}				55	Α
Maximum peak, one-cycle	I	10 ms sine pulse,	rated V _{RRM} applied		500	
non-repetitive surge current	I _{TSM}	10 ms sine pulse, r	no voltage reapplied		600	
Maximum I ² t for fusing	l ² t	10 ms sine pulse,	rated V _{RRM} applied	Initial $T_J = T_J$ maximum	1250	• 2
Maximum I-t for fusing	1-1	10 ms sine pulse, r	Ilse, no voltage reapplied		1760	A ² s
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied		12 500	A²√s	
Low level value of threshold voltage	V _{T(TO)1}				1.02	V
High level value of threshold voltage	V _{T(TO)2}				1.23	v
Low level value of on-state slope resistance	r _{t1}				9.74	mΩ
High level value of on-state slope resistance	r _{t2}				7.50	
Maximum peak on-state voltage	V_{TM}	110 A, T _J = 25 °C			1.85	V
Maximum rate of rise of turned-on current	dl/dt	T _J = 25 °C		100	A/μs	
Maximum holding current	I _H			150		
Maximum latching current	ΙL				300	A
Maximum reverse and direct leakage current	I _{RRM/} I _{DRM}	T _J = 25 °C	$V_R = Rated V_{RRM}/V_{DRM}$		0.5	mA
		T _J = 125 °C	V _R = Rated V _{RRM} /V	V _{DRM} 10		
Maximum rate of rise of off-state voltage 40TPS08			Sanara and Control		500	V/µs
Maximum rate of rise of off-state voltage 40TPS12	dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_g -k = Open		1000	V/µs	

TRIGGERING					
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}			10	W
Maximum average gate power	P _{G(AV)}			2.5	, vv
Maximum peak gate current	I _{GM}			2.5	Α
Maximum peak negative gate voltage	- V _{GM}			10	٧
Maximum required DC gate voltage to trigger	V _{GT}	T _J = - 40 °C		4.0	V
		T _J = 25 °C	Anode supply = 6 V resistive load	2.5	
		T _J = 125 °C		1.7	
	I _{GT}	T _J = - 40 °C		270	
Maximum required DC gate current to trigger		T _J = 25 °C		150	A
		T _J = 125 °C		80	mA
		T_J = 25 °C, for 40TPS08A and 40TPS12A		40	
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value		0.25	V
Maximum DC gate current not to trigger	I _{GD}			6	mA



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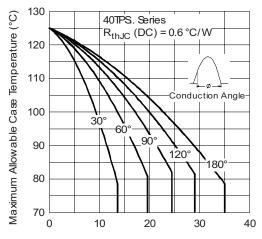
THERMAL AND MECHANIC				VALUE0		
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and stotemperature range	rage	T_J,T_Stg		- 40 to 125	°C	
Maximum thermal resistance, junction to case Maximum thermal resistance, junction to ambient Maximum thermal resistance, case to heatsink		R _{thJC}	DC operation	0.6		
		R _{thJA}		40	°C/W	
		R _{thCS}	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
				0.21	OZ.	
minimum				6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf ⋅ in)	
Marking device				40TPS08A		
			Case style TO-247AC		40TPS12A	
					40TPS08	
				40TPS12		

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Average On-state Current (A)
Fig. 1 - Current Rating Characteristics

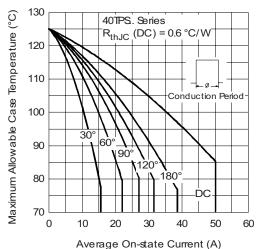


Fig. 2 - Current Rating Characteristics

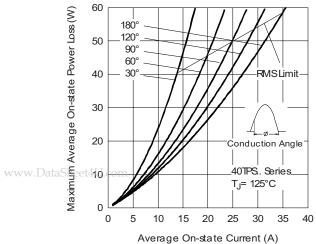


Fig. 3 - On-State Power Loss Characteristics

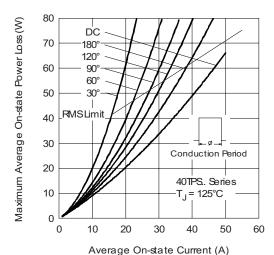
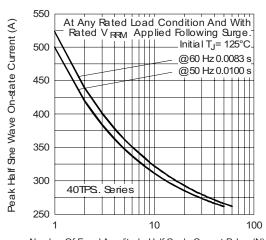


Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulæs (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

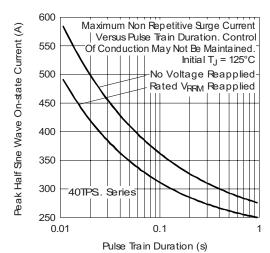


Fig. 6 - Maximum Non-Repetitive Surge Current



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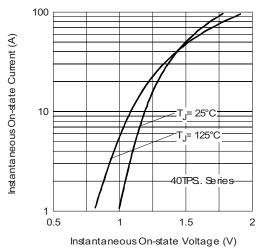


Fig. 7 - On-State Voltage Drop Characteristics

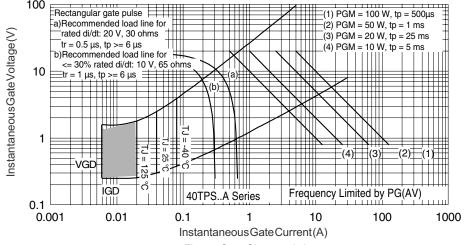


Fig. 8 - Gate Characteristics

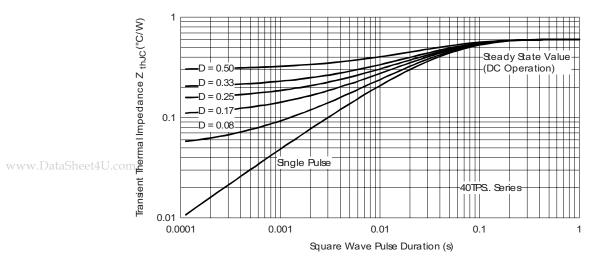


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

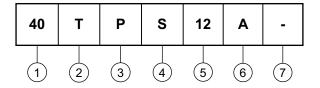
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ORDERING INFORMATION TABLE

Device code



- 1 Current rating (40 = 40 A)
- 2 Circuit configuration:

T = Thyristor

3 - Package:

P = TO-247

4 - Type of silicon:

S = Standard recovery rectifier

6 - • A = Low lgt selection 40 mA maximum

• None = Standard Igt selection

None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95223			
Part marking information	http://www.vishay.com/doc?95226		

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